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Hui Huang, Zhihua Chen, Rocio Ponce Ortiz, Christopher Newman, Hakan Usta, Sylvia Lou, Jangdae Youn, Yong-Young Noh, Kang-Jun Baeg, Lin X. Chen, Antonio Facchetti,* and Tobin J. Marks*

J. Am. Chem. Soc. **2012**, *134*, 10966–10973. DOI: 10.1021/ja303401s

Page 10966. The middle initial was omitted from the last author’s name; the full name should read “Tobin J. Marks”.